

Bipolar Transistor

(-)50 V, (-)2 A, Low VCE(sat), (PNP)NPN Single TP/TP-FA

2SB1201/2SD1801

Features

- Adoption of FBET, MBIT Processes
- Low Collector-to-Emitter Saturation Voltage
- Small and Slim Package Making it Easy to Make 2SB1201 / 2SD1801 – Used Sets Smaller
- Large Current Capacitance and Wide ASO
- These are Pb-Free Devices

Applications

• Voltage Regulators, Relay Drivers, Lamp Drivers, Electrical Equipment

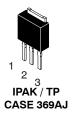
ABSOLUTE MAXIMUM RATINGS (at Ta = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		(-)60	V
Collector-to-Emitter Voltage	V _{CEO}		(–)50	V
Emitter-to-Base Voltage	V _{EBO}		(-)6	V
Collector Current	I _C		(-)2	Α
Collector Current (Pulse)	I _{CP}		(-)4	Α
Collector Dissipation	P _C		0.8	W
		Tc = 25°C	15	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

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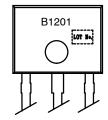
NOTE: Specifications (): 2SB1201

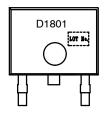




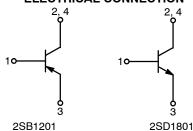
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MARKING DIAGRAMS





ELECTRICAL CONNECTION



ORDERING INFORMATION

Device	Package	Shipping [†]
2SB1201S-E	IPAK / TP (Pb-Free)	500 pcs / Bag
2SB1201S-TL-E	DPAK / TP-FA (Pb-Free)	700 / Tape & Reel
2SB1201T-TL-E	DPAK / TP-FA (Pb-Free)	700 / Tape & Reel
2SD1801S-TL-E	DPAK / TP-FA (Pb-Free)	700 / Tape & Reel
2SD1801S-E	IPAK / TP (Pb-Free)	500 pcs / Bag

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (at Ta = 25°C)

			Ratings			
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} = (-)50 V, I _E = 0 A	-	-	(-)100	nA
Emitter Cutoff Current	I _{EBO}	V _{EB} = (-)4 V, I _C = 0 A	-	-	(-)100	nA
DC Current Gain	h _{FE} 1	$V_{CE} = (-)2 \text{ V}, I_{C} = (-)100 \text{ mA}$	100*	-	560*	-
	h _{FE} 2	V _{CE} = (-)2 V, I _C = (-)1.5 A	40	-	-	-
Gain-Bandwidth Product	f _T	V _{CE} = (-)10 V, I _C = (-)50 mA	-	150	-	MHz
Output Capacitance	Cob	V _{CB} = (-)10 V, f = 1 MHz	-	(22)12	-	pF
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C = (-)1 A, I _B = (-)50 mA	-	(-0.3)0.15	(-0.7)0.4	V
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C = (-)1 A, I _C = (-)50 mA	-	(-)0.9	(-)1.2	V
Collector-to-Base Breakdown Voltage	V _{(BR)CBO}	I _C = (-)10 μA, I _E = 0 A	(-)60	-	-	V
Collector-to-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C = (-)1 mA, R _{BE} = ∞	(-)50	-	-	V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E = (-)10 μA, I _C = 0 A	(-)6	-	-	V
Turn-ON Time	t _{on}	See specified Test Circuit.	-	(60)60	-	ns
Storage Time	t _{stg}		-	(450)550	-	ns
Fall Time	t _f		-	30	-	ns

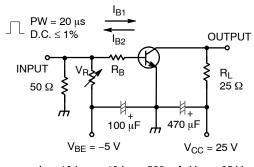
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

NOTE: Specifications (): 2SB1201

Table 1.

Rank	R	S	T	U
h _{FE}	100 to 200	140 to 280	200 to 400	280 to 560

Switching Time Test Circuit

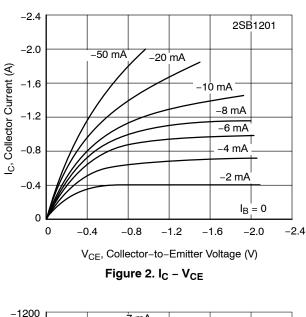


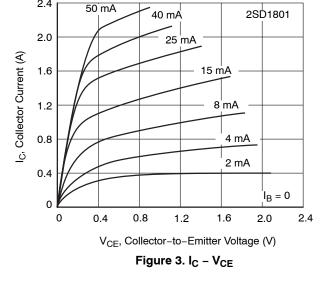
 I_C = 10 I_{B1} = –10 I_{B2} = 500 mA, V_{CC} = 25 V (For PNP, the polarity is reversed)

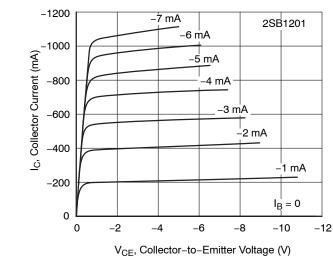
Figure 1. Switching Time Test Circuit

^{*}The 2SB1201 / 2SD1801 are classified by 100 mA $h_{\mbox{\scriptsize FE}}$ as follows :

2.4







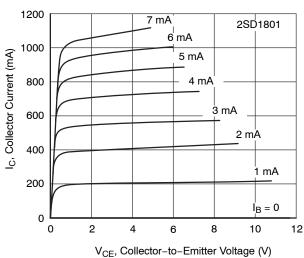
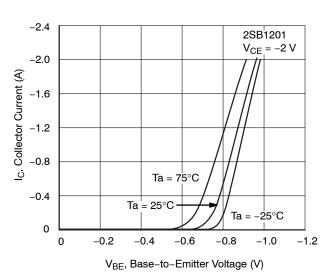


Figure 5. I_C - V_{CE}

Figure 4. I_C - V_{CE}



2.4 2SD1801 V_{CE} = 2 V 2.0 I_C, Collector Current (A) 1.6 1.2 0.8 Ta = 75^o°C 0.4 Ta = 25°C Ta = −25°C 0 0 0.2 0.4 0.6 8.0 1.0 1.2 V_{BE}, Base-to-Emitter Voltage (V)

Figure 6. I_C - V_{BE}

Figure 7. I_C - V_{BE}

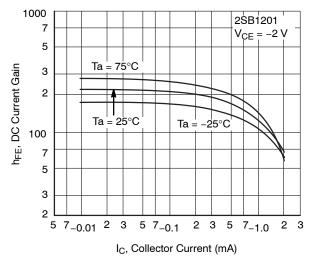


Figure 8. h_{FE} - I_C

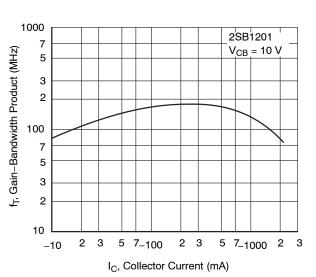


Figure 10. f_T - I_C

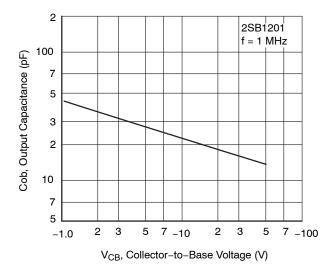


Figure 12. Cob - V_{CB}

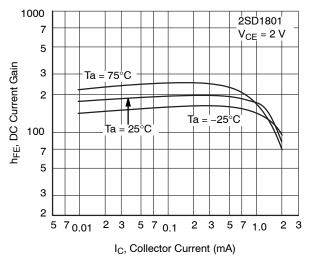


Figure 9. h_{FE} - I_C

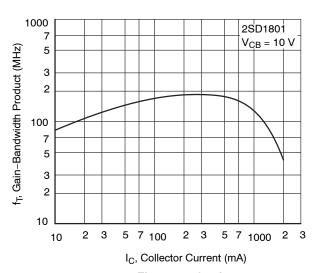


Figure 11. f_T - I_C

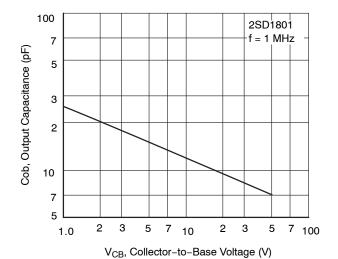


Figure 13. Cob - V_{CB}

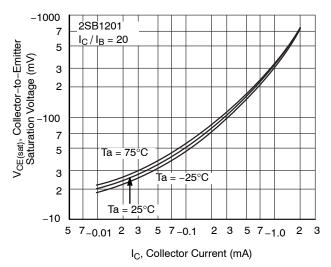


Figure 14. V_{CE(sat)} - I_C

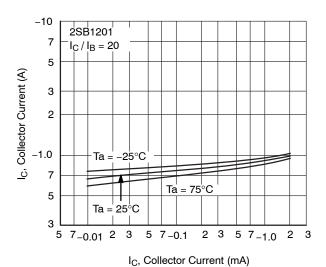


Figure 16. V_{BE(sat)} - I_C

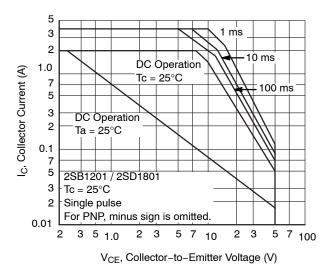


Figure 18. ASO

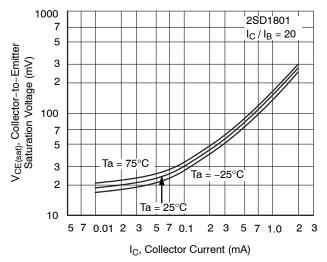


Figure 15. V_{CE(Sat)} - I_C

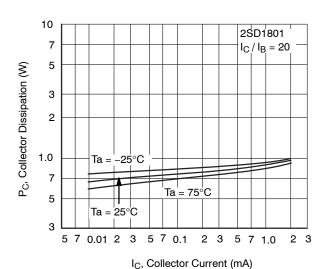


Figure 17. V_{BE(sat)} - I_C

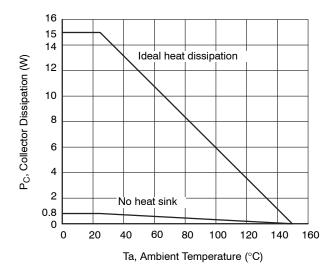
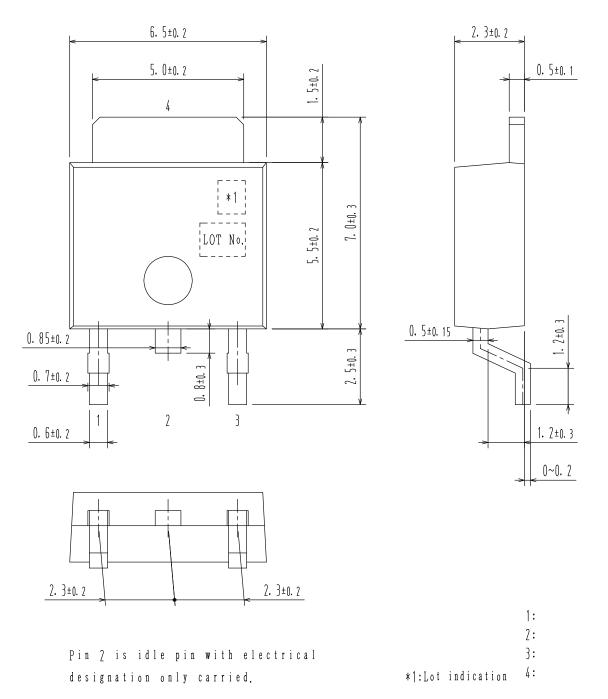


Figure 19. P_C - Ta

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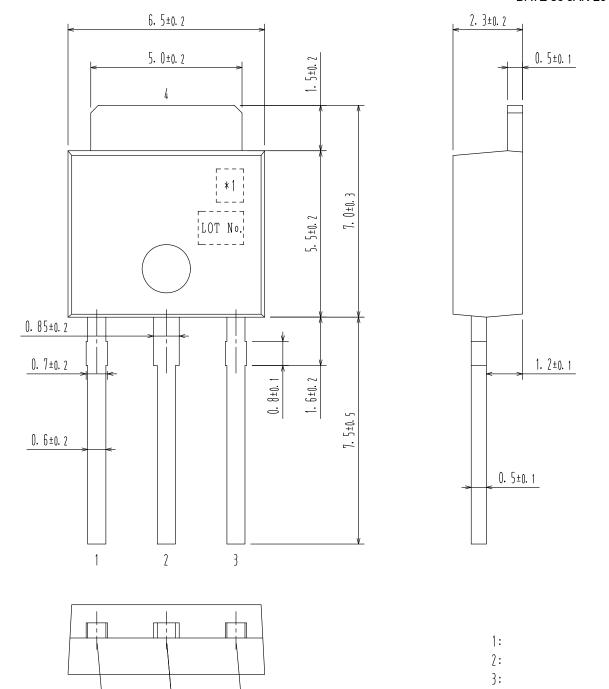


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